SF161CTD THRU SF168CTD

GLASS PASSIVATED SUPER FAST RECTIFIER Reverse Voltage – 50 to 800 V Forward Current – 16 A

Features

- · Low forward voltage drop
- · Low reverse leakage current
- · Superfast switching time for high efficiency
- · High current capability
- · High surge current capability

Mechanical Data

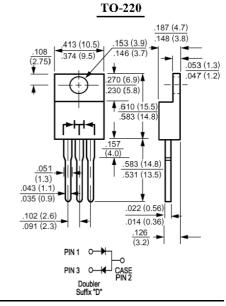
· Case: Molded plastic, TO-220

• Epoxy: UL 94V-0 rate flame retardant

• Terminals: leads solderable per MIL-STD-202

method 208 guaranteed

Polarity: As markedMounting Position: Any



Dimensions in inches and (millimeters)

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	SF161CTD	SF162CTD	SF163CTD	SF164CTD	SF165CTD	SF166CTD	SF167CTD	SF168CTD	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	٧
Maximum RMS Voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current at T_C = 100 $^{\circ}$ C	I _(AV)	16								Α
Peak Forward Surge Current, 8.3 mS Single half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	125								Α
Maximum Forward Voltage at 8 A and 25 °C	V _F	0.95 1.3 1.7					.7	V		
Maximum Reverse Current at $T_A = 25$ °C at Rated DC Blocking Voltage $T_A = 100$ °C	I _R	10 500								μA
Typical Junction Capacitance 1)	C _J	80 60						pF		
Maximum Reverse Recovery Time 2)	t _{rr}	35 50						ns		
Typical Thermal Resistance 3)	$R_{\theta JC}$	2.5								°C/W
Operating and Storage Temperature Range	T _J , T _s	-55 to +150								°C

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 VDC.

³⁾ Thermal resistance from Junction to case per leg mounted on heatsink.



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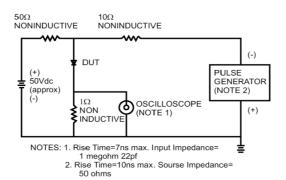




Dated: 24/03/2006 H

 $^{^{2)}}$ Reverse recovery test conditions: I_F = 0.5 A, I_R = 1 A, I_{RR} = 0.25 A

FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



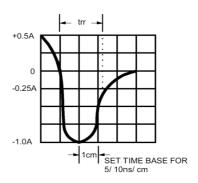
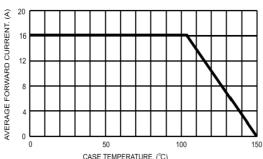


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE



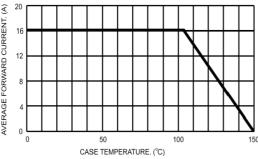


FIG.4- MAXIMUM NON-REPETITIVE FORWARD SURGE **CURRENT PER LEG** 3 FORWARD SURGE CURRENT. TC=125°C 8.3ms Single Half Sine Wa JEDEC Method

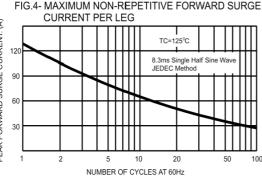


FIG.5- TYPICAL JUNCTION CAPACITANCE PER LEG

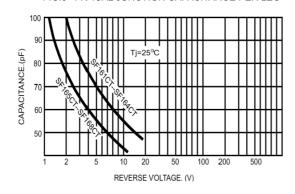


FIG.3- TYPICAL REVERSE CHARACTERISTICS

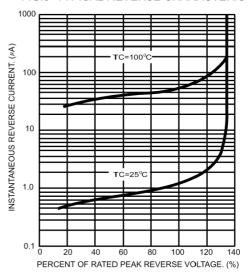
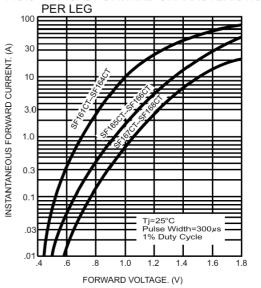


FIG.6- TYPICAL FORWARD CHARACTERISTICS





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